



### NPN Low Vce(sat) Transistor

Voltage 100V

100V Current

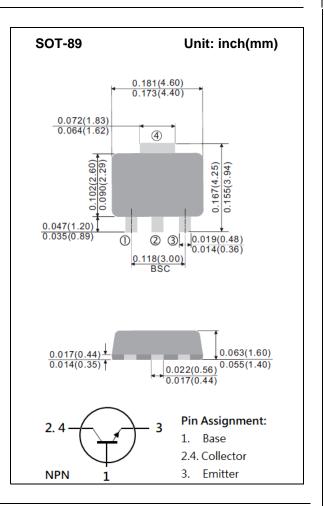
1A

#### **Features**

- Silicon NPN epitaxial type
- Low Vce(sat) 0.35V(max)@Ic/Ib= 500mA / 50mA
- High collector current capability
- Excellent DC current gain characteristics
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 Standard
- PNP complement: PBHV9110DH-AU

#### **Mechanical Data**

- Case: SOT-89 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.002 ounces, 0.057 grams
- Marking: 811D



# Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Collector-Base Voltage	V <sub>CBO</sub>	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	100	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current (DC)	I <sub>C</sub>	1	Α
Collector Current (Pulse)	I <sub>CP</sub>	3	Α
Power Dissipation	$P_D$	1.4	W
Junction Temperature	TJ	150	°C
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	°C
Thermal Resistance from Junction to Ambient (Note)	$R_{\theta JA}$	89	°C/W

Note: Mounted on FR4 PCB at 1 inch square copper pad.





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
OFF Characteristics						
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0A	100	-	-	V
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	I <sub>C</sub> = 0.1mA, I <sub>E</sub> = 0A	120	-	-	V
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> = 0.1mA, I <sub>C</sub> = 0A	6	-	-	V
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0A	-	-	500	nA
Emitter Cutoff Current	I <sub>EBO</sub>	$V_{EB}$ = 6V, $I_{C}$ = 0A	-	-	500	nA
ON characteristics						
DC Current Gain (Note1)	h <sub>FE</sub>	$V_{CE}$ = 2V, $I_{C}$ = 150mA	140	-	330	-
		$V_{CE} = 5V, I_{C} = 500 \text{mA}$	100	-	300	
		V <sub>CE</sub> = 5V, I <sub>C</sub> = 1A	40	-	-	
Collector-Emitter Saturation Voltage (Note1)	V <sub>CE(SAT)</sub>	I <sub>C</sub> = 0.1A, I <sub>B</sub> = 10mA	-	38	120	mV
		$I_{C}$ = 0.5A, $I_{B}$ = 50mA	-	117	350	
		I <sub>C</sub> = 1A, I <sub>B</sub> = 0.1A	-	220	450	
Base-Emitter Saturation voltage	V <sub>BE(SAT)</sub>	I <sub>C</sub> = 0.1A, I <sub>B</sub> = 10mA	-	-	1.0	
(Note1)		I <sub>C</sub> = 0.5A, I <sub>B</sub> = 50mA	-	-	1.1	V
Transition Frequency	f <sub>T</sub>	$V_{CE}$ = 5V, $I_{E}$ = -50mA	100	-	-	MHz
Collector Output Capacitance	Сов	$V_{CB}$ = 10V, $I_E$ = 0A, $f$ =1MHz	-	-	10	pF

Note: 1. Pulse width<a></a>300us, Duty cycle<a></a>2%





#### **TYPICAL CHARACTERISTIC CURVES**

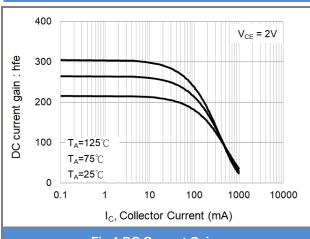


Fig.1 DC Current Gain

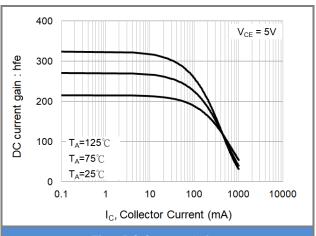


Fig.2 DC Current Gain

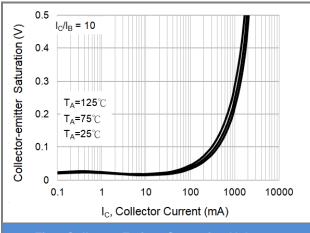


Fig.3 Collector-Emitter Saturation Voltage

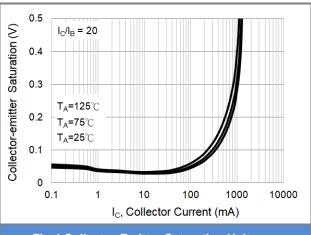
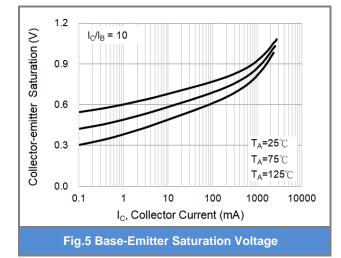
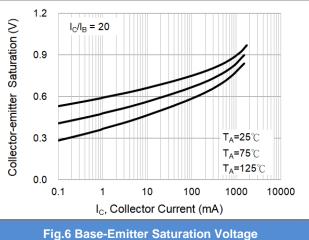


Fig.4 Collector-Emitter Saturation Voltage









#### **TYPICAL CHARACTERISTIC CURVES**

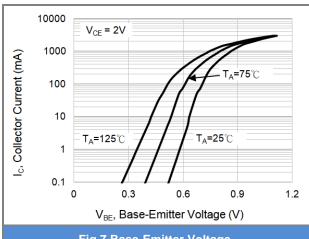
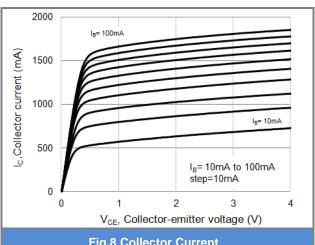
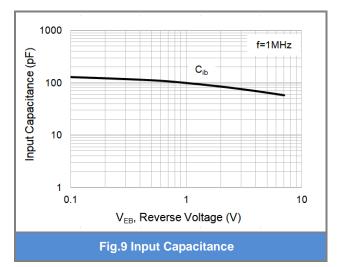
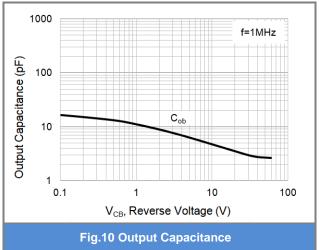


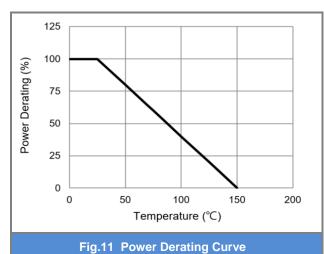
Fig.7 Base-Emitter Voltage



**Fig.8 Collector Current** 







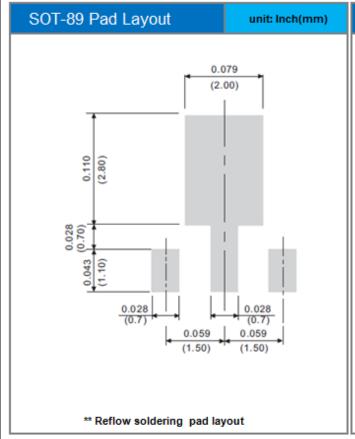


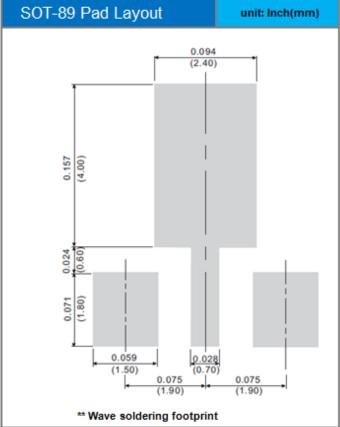


### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PBHV8110DH-AU_R1_000A1	SOT-89	1k pcs / 7" reel	811D	Halogen free

### **MOUNTING PAD LAYOUT**





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